

1A, 50V - 1000V Surface Mount Fast Recovery Rectifier

FEATURES

- Glass passivated junction chip
- Ideal for automated placement
- Low profile package
- Low power loss, high efficiency
- Moisture sensitivity level: level 1, per J-STD-020
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

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- High frequency rectification
- Freewheeling application
- Switching mode converters and inverters in computer and telecommunication.

MECHANICAL DATA

• Case: SOD-123FL

• Molding compound meets UL 94V-0 flammability rating

• Terminal: Matte tin plated leads, solderable per J-STD-002

• Meet JESD 201 class 1A whisker test

Polarity: As marked

• Weight: 0.016 g (approximately)

KEY PARAMETERS					
PARAMETER	VALUE	UNIT			
I _F	1	Α			
V_{RRM}	50 - 1000	V			
I _{FSM}	30	Α			
T_{JMAX}	150	°C			
Package	ackage SOD-123FL				









SOD-123FL

DADAMETED	SYMBOL	RS1A	RS1B	RS1D	RS1G	RS1J	RS1K	RS1M	
PARAMETER	STWBOL	FL	FL	FL	FL	FL	FL	FL	UNIT
Marking code on the device		RAF	RBF	RDF	RGF	RJF	RKF	RMF	
Repetitive peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Reverse voltage, total rms value	$V_{R(RMS)}$	35	70	140	280	420	560	700	V
Forward current	I _F	1						Α	
Surge peak forward current, 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	30						А	
Junction temperature	T _J	- 55 to +150							°C
Storage temperature	T _{STG}	- 55 to +150						°C	

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THERMAL PERFORMANCE					
PARAMETER	SYMBOL	TYP.	UNIT		
Junction-to-lead thermal resistance per diode	$R_{\Theta JL}$	17	°C/W		
Junction-to-ambient thermal resistance per diode	$R_{\Theta JA}$	84	°C/W		
Junction-to-case thermal resistance per diode	R _{eJC}	19	°C/W		

Thermal Performance Note: Units mounted on PCB (5mm x 5mm Cu pad test board)

PARAMETER		CONDITIONS	SYMBOL	TYP.	MAX.	UNIT
	DOLAEL	$I_F = 0.5A, T_J = 25^{\circ}C$	V _F	0.84	-	V
(1)	RS1AFL RS1BFL	I _F = 1.0A, T _J = 25°C		0.91	1.05	V
Forward voltage per diode (1)	RS1DFL	$I_F = 0.5A, T_J = 125^{\circ}C$		0.70	-	V
	RS1GFL	I _F = 1.0A, T _J = 125°C		0.78	0.90	V
		$I_F = 0.5A, T_J = 25^{\circ}C$		0.97	-	V
F	RS1JFL	$I_F = 1.0A, T_J = 25^{\circ}C$.,	1.04	1.30	V
Forward voltage per diode (1)	RS1KFL RS1MFL	$I_F = 0.5A, T_J = 125^{\circ}C$	V _F	0.80	-	V
		I _F = 1.0A, T _J = 125°C		0.89	1.12	V
5	T _J = 25°C	I _R	-	5	μΑ	
Reverse current @ rated V _R per diode ⁽²⁾			T _J = 125°C	-	150	μA
Junction capacitance	RS1AFL RS1BFL RS1DFL RS1GFL	1 MHz, V _R =4.0V	CJ	15	-	pF
ounous, capacitanos	RS1JFL RS1KFL RS1MFL			11	-	pF
Reverse recovery time	RS1AFL RS1BFL RS1DFL RS1GFL	I _F =0.5A ,I _R =1.0A	t _{rr}	-	150	ns
·	RS1JFL RS1KFL RS1MFL	I _{RR} =0.25A	t _{rr}	-	250	ns

Notes:

- 1. Pulse test with PW=0.3 ms
- 2. Pulse test with PW=30 ms

ORDERING INFORMATION					
ORDERING CODE	PACKAGE	PACKING			
RS1AFL RVG	SOD-123FL	3,000 / 7" Plastic reel			
RS1BFL RVG	SOD-123FL	3,000 / 7" Plastic reel			
RS1DFL RVG	SOD-123FL	3,000 / 7" Plastic reel			
RS1GFL RVG	SOD-123FL	3,000 / 7" Plastic reel			
RS1JFL RVG	SOD-123FL	3,000 / 7" Plastic reel			
RS1KFL RVG	SOD-123FL	3,000 / 7" Plastic reel			
RS1MFL RVG	SOD-123FL	3,000 / 7" Plastic reel			

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CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

Fig.1 Forward Current Derating Curve

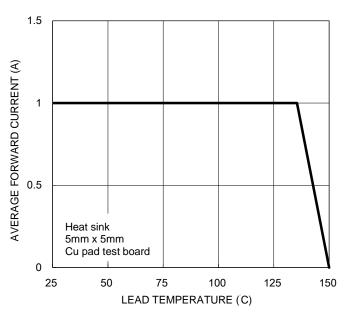


Fig.2 Typical Junction Capacitance

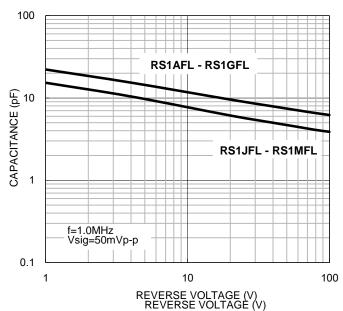
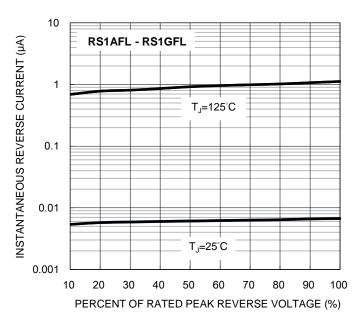
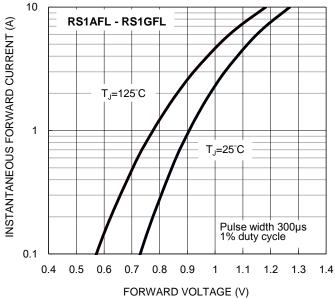


Fig.3 Typical Reverse Characteristics



Fig.4 Typical Forward Characteristics







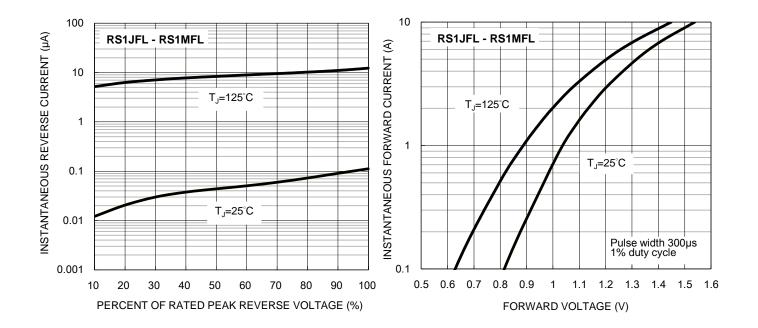


CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

Fig.5 Typical Reverse Characteristics

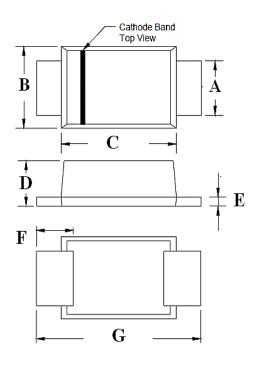
Fig.6 Typical Forward Characteristics





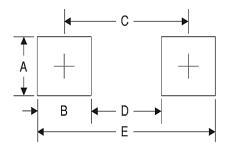
PACKAGE OUTLINE DIMENSIONS

SOD-123FL



DIM.	Unit	(mm)	Unit (inch)		
DIIVI.	Min	Max	Min	Max	
Α	0.80	1.15	0.031	0.045	
В	1.70	2.10	0.067	0.083	
С	2.60	3.10	0.102	0.122	
D	0.88	1.35	0.035	0.053	
Е	0.10	0.30	0.004	0.012	
F	0.30	0.90	0.012	0.035	
G	3.45	3.95	0.136	0.156	

SUGGESTED PAD LAYOUT



Symbol	Unit (mm)	Unit (inch)
A	1.4	0.055
В	1.2	0.047
С	3.1	0.122
D	1.9	0.075
E	4.3	0.169

MARKING DIAGRAM



= Marking Code= Date Code P/N ΥW = Factory Code



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